

## Seung Sae Hong

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University of California, Davis  
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### Education

Stanford University, Stanford, CA

PhD in Applied Physics (2014)

Dissertation: *Electronic transport in topological insulator nanostructures*

Seoul National University, Seoul, Korea

BS in Physics (minor in Electrical Engineering), *summa cum laude* (2007)

Thesis: *Demonstration and calibration of NEMS torsional resonators combined with carbon nanotubes*

### Research Interests

Materials physics: Complex oxide heterostructures and interfaces; Low-dimensional quantum materials; Correlated electronic systems in the reduced dimension; Nanomaterials and devices for energy applications

### Research Positions

UC Davis	Assistant Professor, Materials Science and Engineering	(2020 – present)
Stanford University	Postdoctoral Research Scholar (Advisor: Harold Hwang)	(2014 – 2019)
Stanford University	Graduate Research Assistant (Advisor: Yi Cui)	(2007 – 2013)
Seoul National University	Undergraduate Research Assistant	(2006 – 2007)

### Professional Activities

Member of American Physical Society (APS), Materials Research Society (MRS)

Journal reviewer for Nano Letters, Nature Communications, Scientific Reports, Physics Review Materials, APL journals, ACS journals.

### Awards

Graduate Student Award Gold medal, Materials Research Society (Fall MRS Meeting, Boston 2012)

Academic excellence full scholarship, Seoul National University (2006)

### Teaching

UC Davis	Instructor/course design, Sustainable Energy Technology Lab (EMS 170L, 2020)
UC Davis	Instructor, Structure and Characterization of Engineering Materials (EMS 162, 2020)
Stanford University	Advised/trained six graduate students during PhD/Postdoctoral periods
Stanford University	Teaching assistant, Classical Mechanics Lab (Physics 42, 2013)
Stanford University	Tutoring staff, Physics tutoring center (2013),

**Publications** ([Google Scholar profile](#))31. *Strain-induced room-temperature ferroelectricity in SrTiO<sub>3</sub> membranes*

R. Xu, J. Huang, E. Barnard, S. S. Hong, P. Singh, E. Wong, T. Jansen, V. Harbola, J. Xiao, B. Y. Wang, S. Crossley, D. Lu, S. Liu, & H. Y. Hwang  
*Nature Communications*, 11, 3141 (2020).

30. *Extreme tensile strain states in La<sub>0.7</sub>Ca<sub>0.3</sub>MnO<sub>3</sub> membranes*

S. S. Hong, M. Gu, M. Verma, V. Harbola, B. Y. Wang, D. Lu, A. Vailionis, Y. Hikita, R. Pentcheva, J. M. Rondinelli, & H. Y. Hwang  
*Science*, 368, 71 (2020).

29. *Freestanding crystalline YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7-x</sub> heterostructure membranes*

Z. Chen, B. Y. Wang, B. H. Goodge, D. Lu, S. S. Hong, D. Li, Y. Hikita, L. F. Kourkoutis, & H. Y. Hwang  
*Physical Review Materials*, 3, 060801 (2019).

28. *Large-area crystalline BaSnO<sub>3</sub> membranes with high electron mobilities*

P. Singh, A. Swartz, D. Lu, S. S. Hong, K. Lee, A. F. Marshall, K. Nishio, Y. Hikita, & H. Y. Hwang  
*ACS Applied Electronic Materials*, 1, 1269 (2019).

27. *Delta-doped SrTiO<sub>3</sub> top-gated field effect transistor*

H. Inoue, H. Yoon, T. A. Merz, A. G. Swartz, S. S. Hong, Y. Hikita, & H. Y. Hwang  
*Applied Physics Letters*, 114, 231605 (2019).

26. *Two-dimensional limit of crystalline order in perovskite membrane films*

S. S. Hong, J. H. Yu, D. Lu, A. F. Marshall, Y. Hikita, Y. Cui, & H. Y. Hwang  
*Science Advances*, 3, eaao5173 (2017).

25. *Synthesis of freestanding single-crystal perovskite films and heterostructures by etching of sacrificial water-soluble layers*

D. Lu, D. J. Baek, S. S. Hong, L. F. Kourkoutis, Y. Hikita, & H. Y. Hwang  
*Nature Materials*, 15, 1255 (2016).

24. *Lateral and vertical two-dimensional layered topological insulator heterostructures*

Y. Li, J. Zhang, G. Zheng, Y. Sun, S. S. Hong, F. Xiong, S. Wang, H. R. Lee, & Y. Cui  
*ACS Nano*, 9, 10916 (2015).

23. *Topological insulator nanostructures*

S. S. Hong & Y. Cui  
Book chapter in *Topological Insulators*, John Wiley & Sons (2015).

22. *Vertical heterostructure of two-dimensional MoS<sub>2</sub> and WSe<sub>2</sub> with vertically aligned layers*

J. H. Yu, H. R. Lee, S. S. Hong, D. Kong, H.-W. Lee, H. Wang, F. Xiong, S. Wang, & Y. Cui  
*Nano Letters*, 15, 1031 (2015).

21. *Physical and chemical tuning of two-dimensional transition metal dichalcogenides*

H. Wang, H. Yuan, S. S. Hong, Y. Li, & Y. Cui  
*Chemical Society Reviews*, 44, 2664 (2015).

20. *Topological insulator nanostructures*

S. S. Hong, D. Kong, & Y. Cui

*MRS Bulletin*, 39, 873 (2014).

19. *One-dimensional helical transport in topological insulator nanowire interferometers*

S. S. Hong, Y. Zhang, J. J. Cha, X.-L. Qi, & Y. Cui

*Nano Letters*, 14, 2815 (2014).

18. *Ambipolar field effect in Sb-doped Bi<sub>2</sub>Se<sub>3</sub> nanoplates by solvothermal synthesis*

D. Kong, K. J. Koski, J. J. Cha, S. S. Hong, & Y. Cui

*Nano Letters*, 13, 632 (2013).

17. *Progress, challenges, and opportunities in two-dimensional materials beyond graphene*

S. Z. Butler, S. M. Hollen, L. Cao, Y. Cui, J. A. Gupta, H. R. Gutiérrez, T. F. Heinz, S. S. Hong, J. Huang, A. F.

Ismach, E. Johnston-Halperin, M. Kuno, V. V. Plashnitsa, R. D. Robinson, R. S. Ruoff, S. Salahuddin, J. Shan, L.

Shi, M. G. Spencer, M. Terrones, W. Windl, & J. E. Goldberger

*ACS Nano*, 7, 2898 (2013).

16. *Silicon nanowires and related nanostructures as lithium-ion battery anodes*

L. Hu, L. Cui, S. S. Hong, J. McDonough, & Y. Cui

Book chapter in *Silicon and Silicide Nanowires*, Pan Stanford Publishing (2013).

15. *Unconventional Josephson effect in hybrid superconductor-topological insulator devices*

J. R. Williams, A. J. Bestwick, P. Gallagher, S. S. Hong, Y. Cui, A. S. Bleich, J. G. Analytis, I. R. Fisher, & D.

Goldhaber-Gordon

*Physical Review Letters*, 109, 056803 (2012).

14. *Ultra-low carrier concentration and surface dominant transport in antimony-doped Bi<sub>2</sub>Se<sub>3</sub> topological insulator nanoribbons*

S. S. Hong, J. J. Cha, D. Kong, & Y. Cui

*Nature Communications*, 3, 757 (2012).

13. *Effects of magnetic doping on weak antilocalization in narrow Bi<sub>2</sub>Se<sub>3</sub> nanoribbons*

J. J. Cha, M. Claassen, D. Kong, S. S. Hong, K. J. Koski, X.-L. Qi, & Y. Cui

*Nano Letters*, 12, 4355 (2012).

12. *Weak antilocalization in Bi<sub>2</sub>(Se<sub>x</sub>Te<sub>1-x</sub>)<sub>3</sub> nanoribbons and nanoplates*

J. J. Cha, D. Kong, S. S. Hong, J. G. Analytis, K. Lai, & Y. Cui

*Nano Letters*, 12, 1107 (2012).

11. *In situ X-ray diffraction studies of (De)lithiation mechanism in silicon nanowire anodes*

S. Misra, N. Liu, J. Nelson, S. S. Hong, Y. Cui, & M. F. Toney

*ACS Nano*, 6, 5465 (2012).

10. *Ambipolar field effect in the ternary topological insulator (Bi<sub>x</sub>Sb<sub>1-x</sub>)<sub>2</sub>Te<sub>3</sub> by composition tuning*

D. Kong, Y. Chen, J. J. Cha, Q. Zhang, J. G. Analytis, K. Lai, Z. Liu, S. S. Hong, K. J. Koski, S. K. Mo, Z.

Hussain, I. R. Fisher, Z. X. Shen, & Y. Cui

*Nature Nanotechnology*, 6, 705 (2011).

9. *Hollow carbon nanofiber-encapsulated sulfur cathodes for high specific capacity rechargeable lithium batteries*

G. Zheng, Y. Yang, J. J. Cha, S. S. Hong, & Y. Cui

*Nano Letters*, 11, 4462 (2011).

8. *One nanometer resolution electrical probe via atomic metal filament formation*

S. S. Hong, J. J. Cha, & Y. Cui

*Nano Letters*, 11, 231 (2010).

7. *Ultrathin topological insulator  $Bi_2Se_3$  nanoribbons exfoliated by atomic force microscopy*

S. S. Hong, W. Kundhikanjana, J. J. Cha, K. Lai, D. Kong, S. Meister, M. A. Kelly, Z. Shen, & Y. Cui

*Nano Letters*, 10, 3118 (2010).

6. *New nanostructured  $Li_2S$ /silicon rechargeable battery with high specific energy*

Y. Yang, M. T. McDowell, A. Jackson, J. J. Cha, S. S. Hong, & Y. Cui

*Nano Letters*, 10, 1486 (2010).

5. *Si nanoparticle-decorated Si nanowire networks for Li-ion battery anodes*

L. Hu, H. Wu, S. S. Hong, L. Cui, J. R. McDonough, S. Bohy, & Y. Cui

*Chemical Communications*, 47, 367 (2010).

4. *Impedance analysis of silicon nanowire lithium ion battery anodes*

R. Ruffo, S. S. Hong, C. K. Chan, R. A. Huggins, & Y. Cui

*Journal of Physical Chemistry C*, 113, 11390 (2009).

3. *Surface chemistry and morphology of the solid electrolyte interphase on silicon nanowire lithium-ion battery anodes*

C. K. Chan, R. Ruffo, S. S. Hong, & Y. Cui

*Journal of Power Sources*, 189, 1132 (2009).

2. *Structural and electrochemical study of the reaction of lithium with silicon nanowires*

C. K. Chan, R. Ruffo, S. S. Hong, R. A. Huggins, & Y. Cui

*Journal of Power Sources*, 189, 34 (2009).

1. *High-frequency micromechanical resonators from aluminum-carbon nanotube nanolaminates*

J. H. Bak, Y. D. Kim, S. S. Hong, B. Y. Lee, S. R. Lee, J. H. Jang, M. Kim, K. Char, S. Hong, & Y. D. Park

*Nature Materials*, 7, 459 (2008).

### Invited talks

11. *Freestanding crystalline oxide membranes and heterostructures*

47<sup>th</sup> Conference on the Physics and Chemistry of Surfaces and Interfaces, Boulder, Co, January 2020

10. *Freestanding crystalline oxide membranes and heterostructures*

19<sup>th</sup> International Conference on Crystal Growth and Epitaxy, Keystone, Co, July 2019

9. *Complex oxide membranes: More freedom for artificial materials*

University of California, Davis, Davis, CA, May 2019

8. *Complex oxide membranes: More freedom for artificial materials*

University of Nebraska-Lincoln, Lincoln, NE, March 2019

7. *Complex oxide membranes: More freedom for artificial materials*

College of William and Mary, Williamsburg, VA, January 2019

6. *Extreme strain design to control electromagnetism in complex oxide membranes*  
ALS User Meeting Workshop, Berkeley, CA, October 2018
5. *Complex oxide membranes: stretching the boundary of quantum materials*  
Geballe Laboratory for Advanced Materials student seminar, Stanford, CA, April 2018
4. *Electronic transport in topological insulator nanostructures*  
US-Korea Conference 2014, San Francisco, CA, July 2014
3. *Electronic transport in topological insulator nanostructures*  
Seoul National University, Seoul, Korea, February 2014
2. *Topological insulator nanostructures: material design toward a new quantum device*  
Energy Materials Nanotechnology meeting, Houston, TX, January 2013
1. *Topological insulator nanostructures*  
2D Materials Beyond Graphene Workshop, Columbus, OH, August 2012